

CentralTM Semiconductor Corp.

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Manufacturers of World Class Discrete Semiconductors

CDH300
CDH333

SILICON LOW LEAKAGE DIODE

JEDEC D0-35 CASE

DESCRIPTION

The CENTRAL SEMICONDUCTOR CDH300, CDH333 types are epitaxial planar silicon diodes designed for low leakage, high conductance applications. Higher breakdown voltage devices are available on special order.

MAXIMUM RATING (T_A=25°C)

	SYMBOL		UNIT
Peak Repetitive Reverse Voltage	VRRM	150	V
Peak Working Reverse Voltage	VRWM	125	V
Average Forward Current	I _O	200	mA
Forward Steady-State Current	I _F	500	mA
Recurrent Peak Forward Current	i _f	600	mA
Peak Forward Surge Current (1.0s pulse)	I _{FSM}	1000	mA
Peak Forward Surge Current (1.0μs pulse)	I _{FSM}	4000	mA
Power Dissipation	P _D	500	mW
Operating and Storage Junction Temperature	T _J , T _{STG}	-65 TO +200	°C

ELECTRICAL CHARACTERISTICS (T_A=25°C unless otherwise noted)

SYMBOL	TEST CONDITIONS	CDH300		CDH333		UNIT
		MIN	MAX	MIN	MAX	
I _R	V _R =125V		1.0		3.0	nA
I _R	V _R =125V, T _A =100°C		-		500	nA
I _R	V _R =125V, T _A =150°C		3.0		-	μA
B _{VR}	I _R =100μA	150		150		V
V _F	I _F =1.0mA		0.70		-	V
V _F	I _F =5.0mA		0.78		-	V
V _F	I _F =10mA		0.80		-	V
V _F	I _F =50mA		0.88	0.80	0.89	V
V _F	I _F =100mA		0.92	0.83	0.94	V
V _F	I _F =150mA		-	0.86	0.97	V
V _F	I _F =200mA		1.0	0.87	1.05	V
V _F	I _F =250mA		-	0.88	1.08	V
V _F	I _F =300mA		-	0.90	1.15	V
C	V _R =0V		6.0		6.0	pF
t _{rr}	I _F =I _R =10mA, Recov. to 1.0mA	1.0 TYP	3.0	1.0 TYP	3.0	μs

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options
- Custom bar coding for shipments
- Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities
- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

1. If requesting Tin/Lead plated devices, add the suffix " TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
2. If requesting Lead (Pb) Free plated devices, add the suffix " PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

Corporate Headquarters & Customer Support Team

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